NSN 5961-01-173-3022

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-173-3022 **Inclosure Material:** Glass **Overall Length:** 0.357 inches **Terminal Length:** 1.625 inches **Overall Diameter:** 0.235 inches **End Application:** Computer display set, an/uyq-2 (v); aircraft, (ac-130h, mc-103h, ec-Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-13 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 49.4 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 1.5 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: pn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/507 government specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-173-3022

Diode Semiconductor Device - Page 2 of 2



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